NSN 5961-01-053-8736

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-053-8736 **Inclosure Material:** Metal **Overall Length:** Between 0.170 inches and 0.210 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 17.00 amperes collector current, dc **Power Rating Per Characteristic:** 0.3 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Test Data Document:** 98230-0n199196 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No